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## BSS138\_F085 N-Channel Logic Level Enhancement Mode Field Effect Transistor

#### **General Description**

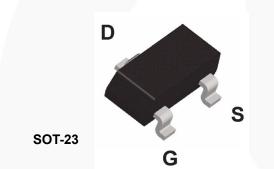
These N-Channel enhancement mode field effect transistors are produced using Fairchild's proprietary, high cell density, DMOS technology. These products have been designed to minimize on-state resistance while provide rugged, reliable, and fast switching performance. These products are particularly suited for low voltage, low current applications such as small servo motor control, power MOSFET gate drivers, and other switching applications.

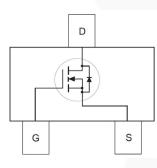
#### Features

- Automotive Qualified
- 0.22 A, 50 V. RDS(ON) = 3.5Ω @ VGS = 10 V

RDS(ON) = 6.0Ω @ VGS = 4.5 V

- High density cell design for extremely low RDS(ON)
- Rugged and Reliable
- Compact industry standard SOT-23 surface mount package





#### **Absolute Maximum Rations**

T<sub>A</sub> = 25°C unless otherwise noted

Symbol	Parameter	Units	Symbol
V <sub>DSS</sub>	Drain-Source Voltage	50	V
V <sub>GSS</sub>	Gate-Source Voltage	±20	V
ID	Drain Current – Continuous (Note 1)	0.22	•
	– Pulsed	0.88	- A
_	Maximum Power Dissipation (Note 1)	0.36	W
P <sub>D</sub>	Derate Above 25°C	2.8	mW/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C
TL	Maximum Lead Temperature for Soldering Purposes, 1/16" from Case for 10 Seconds	300	°C
Thermal C	haracteristics		•

R <sub>0JA</sub> Thermal Resistance, Junction-to-Ambient (Note 1)	350	°C/W
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#### Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
SS	BSS138_F085	7"	8mm	3000 units

July 2016

Symbol	Parameter	Test Conditions	Min	Тур	Мах	Unit
Off Cha	aracteristics					
BV <sub>DSS</sub>	Drain–Source Breakdown Voltage	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250 μA	50			V
ΔBVdss / ΔTJ	Breakdown Voltage Temperature Coefficient	$I_D$ = 250 µA, Referenced to 25°C		72		mV/°C
		V <sub>DS</sub> = 50V, V <sub>GS</sub> = 0 V			0.5	μA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 50V$ , $V_{GS} = 0V$ , $T_{J} = 125^{\circ}C$			5	μA
		V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0 V			100	nA
I <sub>GSS</sub>	Gate-Body Leakage	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$			±100	nA

V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, \qquad I_D = 1 \text{ mA}$	0.8	1.3	1.5	V
$\Delta V_{GS(th)}$ / $\Delta T_J$	Gate Threshold Voltage Temperature Coefficient	$I_D = 1 \text{ mA}$ , Referenced to 25°C		-2		mV/°C
		$V_{GS} = 10 \text{ V}, \qquad I_D = 0.22 \text{ A}$		0.7	3.5	
R <sub>DS(on)</sub>	Static Drain–Source On–Resistance	$V_{GS}$ = 4.5 V, $I_D$ = 0.22 A		1.0	6.0	Ω
		$V_{GS}$ = 10 V, I <sub>D</sub> = 0.22 A, T <sub>J</sub> = 125°C		1.1	5.8	
I <sub>D(on)</sub>	On-State Drain Current	$V_{GS}$ = 10 V, $V_{DS}$ = 5 V	0.2			А
9 <sub>FS</sub>	Forward Transconductance	$V_{DS} = 10 V$ , $I_D = 0.22 A$	0.12	0.5		S

### **Dynamic Characteristics**

C <sub>iss</sub>	Input Capacitance			27	pF
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> = 25 V, f = 1.0 MHz	$V_{GS} = 0 V,$	13	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			6	pF
R <sub>G</sub>	Gate Resistance	V <sub>GS</sub> = 15 mV,	f = 1.0 MHz	9	Ω

#### Switching Characteristics (Note2)

t <sub>d(on)</sub>	Turn-On Delay Time			2.8	5.8	ns
t <sub>r</sub>	Turn-On Rise Time	V <sub>DD</sub> = 30 V,	I <sub>D</sub> = 0.29 A,	2.1	4.4	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	V <sub>DD</sub> = 30 V, V <sub>GS</sub> = 10 V,	I <sub>D</sub> = 0.29 A, R <sub>GEN</sub> = 6 Ω	9.6	19.2	ns
t <sub>f</sub>	Turn-Off Fall Time			8.4	16.8	ns
Qg	Total Gate Charge			1.7	2.4	nC
Q <sub>gs</sub>	Gate-Source Charge	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 10 V	I <sub>D</sub> = 0.22 A,	0.1		nC
Q <sub>gd</sub>	Gate-Drain Charge	- 65 101		0.4		nC

## **Drain–Source Diode Characteristics and Maximum Ratings**

ls	Maximum Continuous Drain–Source Diode Forward Current						0.22	А
Vsd	Drain–Source Diode Forward Voltage	V <sub>GS</sub> = 0 V,	I <sub>S</sub> = 0.44 A	(Note 2)		0.8	1.4	V

Notes:

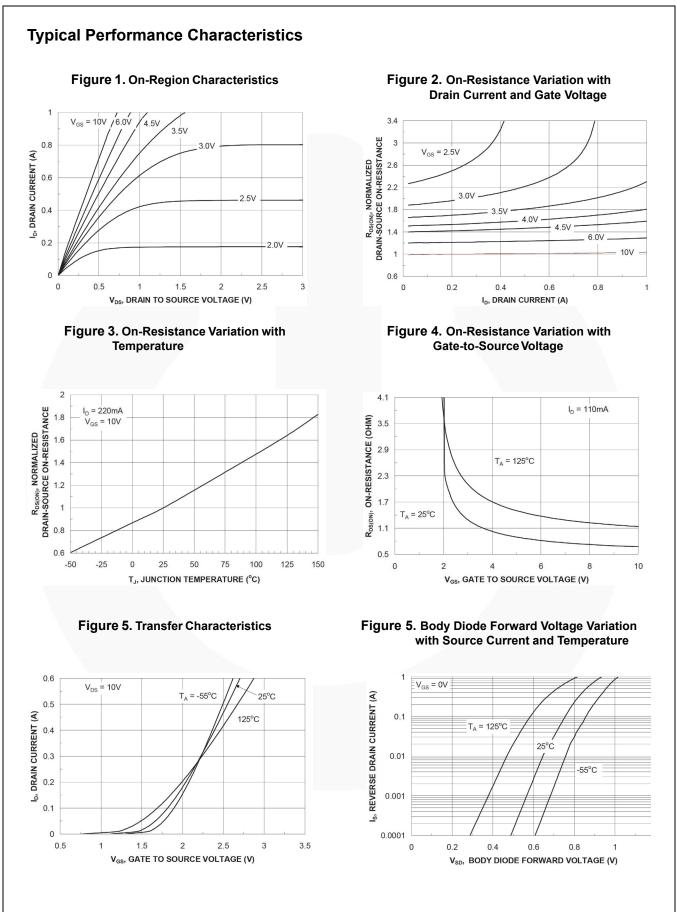
1. R<sub>stak</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>stak</sub> is guaranteed by design while R<sub>stak</sub> is determined by the user's board design.

a) 350°C/W when mounted on a minimum pad. ð Scale 1 : 1 on letter size paper

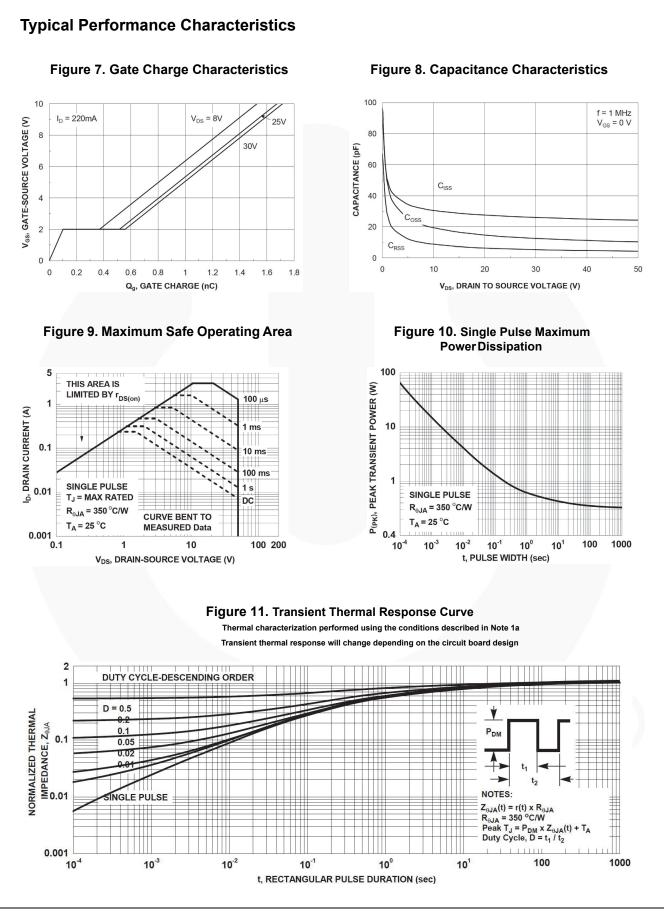
2. Pulse Test: Pulse Width  $\leq$  300  $\mu s,$  Duty Cycle  $\leq$  2.0%.

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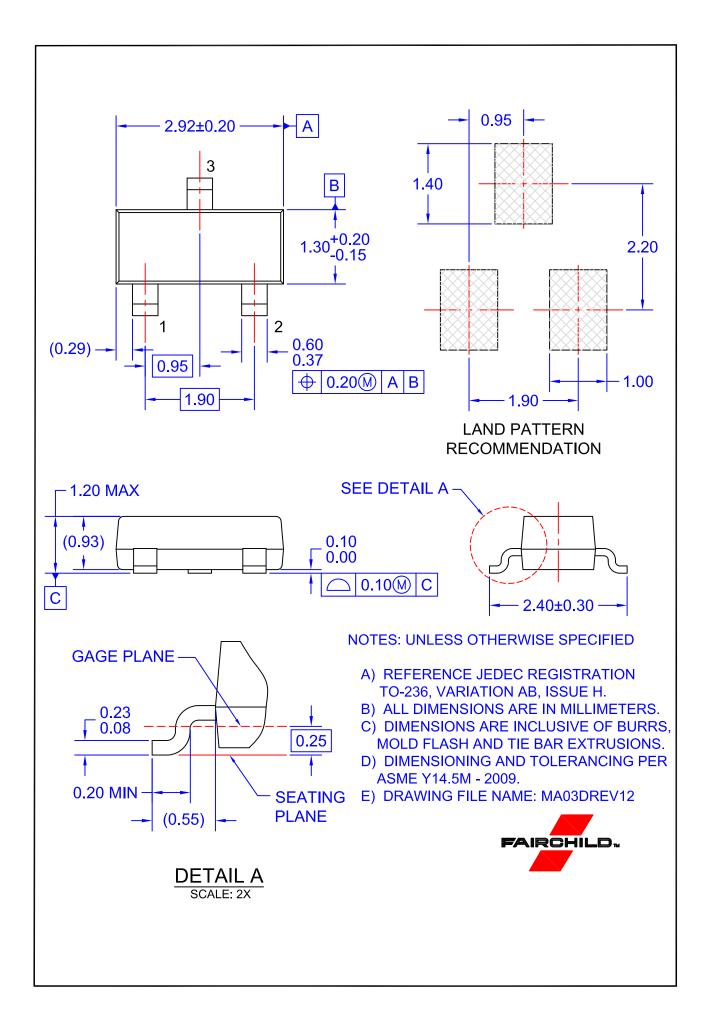
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